

SHINDENGEN

HVX-2 Series Power MOSFET

N-Channel Enhancement type

**2SK2671
(F5F90HVX2)**

900V 5A

FEATURES

Input capacitance (C_{iss}) is small.
Especially, input capacitance at 0 bias is small.

The static Rds(on) is small.

The switching time is fast.

Avalanche resistance guaranteed.

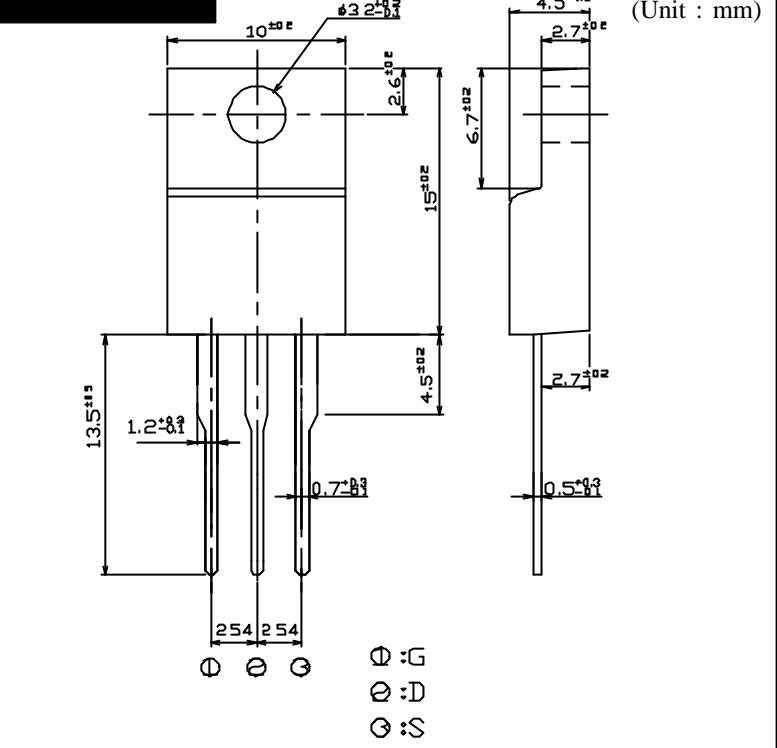
APPLICATION

Switching power supply of AC 240V input
High voltage power supply

Inverter

OUTLINE DIMENSIONS

Case : FTO-220



RATINGS

Absolute Maximum Ratings ($T_c = 25^\circ C$)

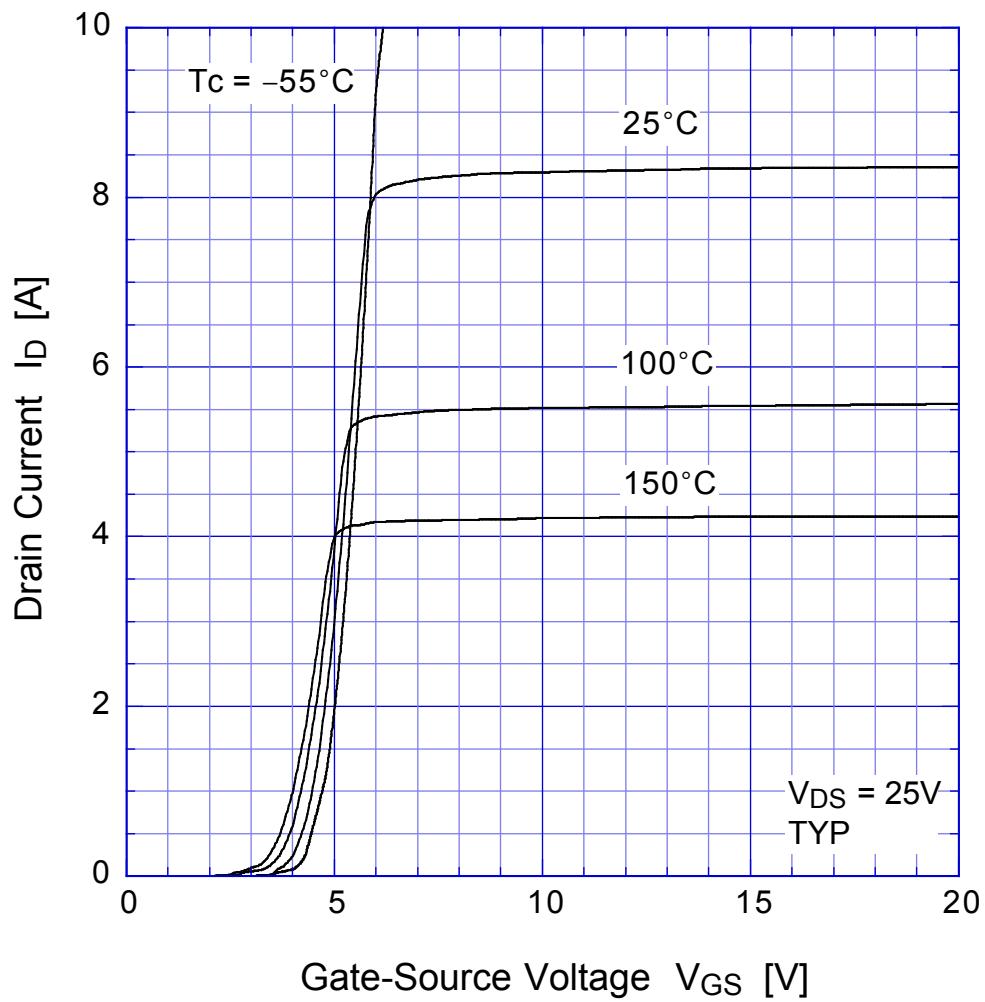
Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T _{tsg}		-55 ~ 150	
Channel Temperature	T _{ch}		150	
Drain-Source Voltage	V _{DSS}		900	V
Gate-Source Voltage	V _{GSS}		± 30	
Continuous Drain Current (DC)	I _D		5	
Continuous Drain Current (Peak)	I _{DP}	Pulse width 10 μs, Duty cycle 1/100	10	A
Continuous Source Current (DC)	I _S		5	
Total Power Dissipation	P _T		40	W
Repetitive Avalanche Current	I _{AR}	T _{ch} = 150	5	A
Single Avalanche Energy	E _{AS}	T _{ch} = 25	100	mJ
Repetitive Avalanche Energy	E _{AR}	T _{ch} = 25	10	
Dielectric Strength	V _{dis}	Terminals to case, AC 1 minute	2	kV
Mounting Torque	T _{OR}	(Recommended torque 0.3 N·m)	0.5	N·m

●Electrical Characteristics T_c = 25°C

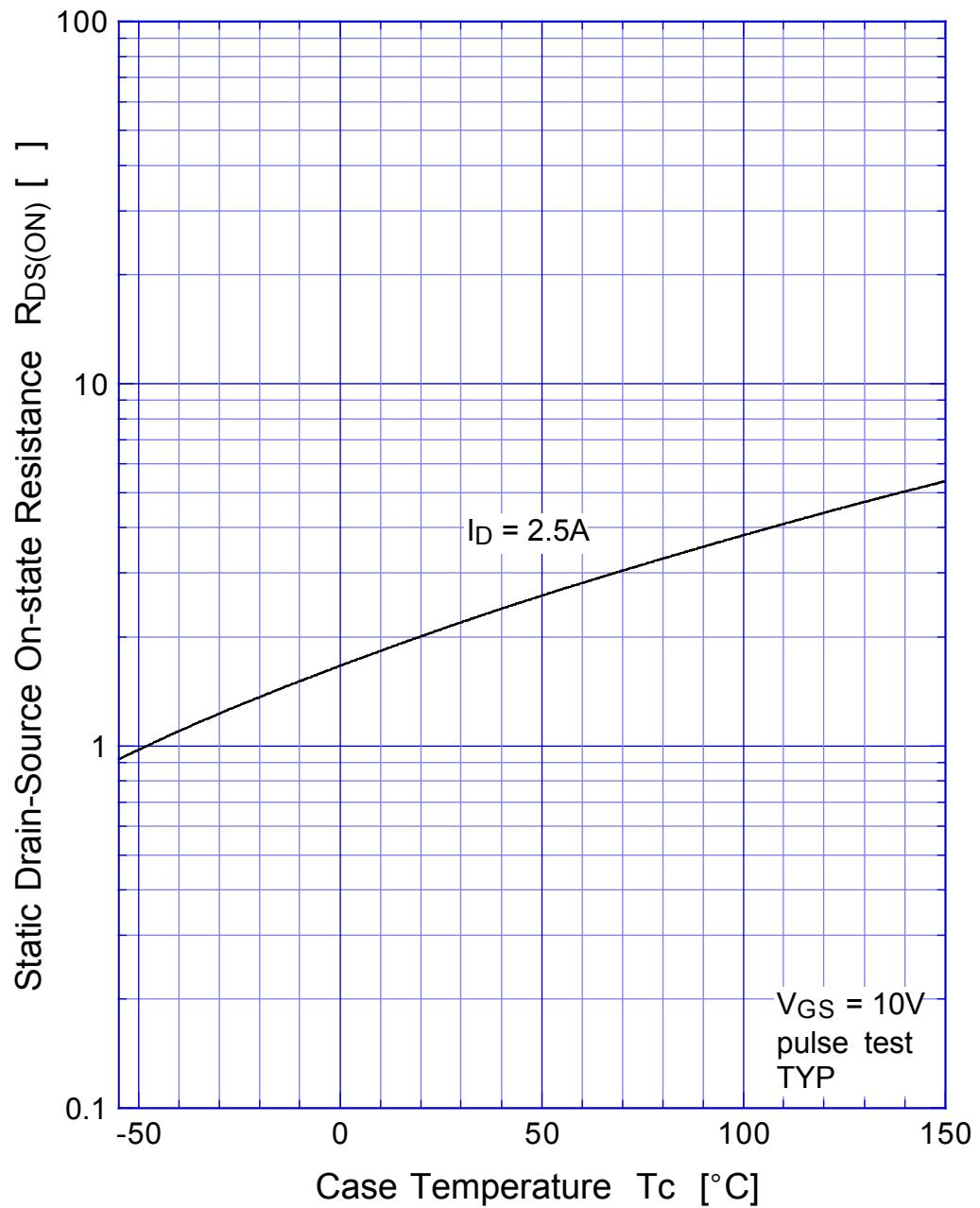
Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage	V _{(BR)DSS}	ID = 1mA, VGS = 0V	900			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 900V, VGS = 0V			250	μA
Gate-Source Leakage Current	I _{GSS}	VGS = ±30V, VDS = 0V			±0.1	
Forward Transconductance	g _{fS}	ID = 2.5A, VDS = 10V	2.4	4.0		S
Static Drain-Source On-state Resistance	R _{D(S)ON}	ID = 2.5A, VGS = 10V		2.1	2.8	Ω
Gate Threshold Voltage	V _{TH}	ID = 1mA, VDS = 10V	2.5	3.0	3.5	V
Source-Drain Diode Forward Voltage	V _{SD}	IS = 2.5A, VGS = 0V			1.5	
Thermal Resistance	θ _{jc}	junction to case			3.12	°C/W
Total Gate Charge	Q _g	VDD = 400V, VGS = 10V, ID = 5A		45		nC
Input Capacitance	C _{iss}	VDS = 25V, VGS = 0V, f = 1MHz		1140		pF
Reverse Transfer Capacitance	C _{rss}			23		
Output Capacitance	C _{oss}			105		
Turn-On Time	t _{on}	ID = 2.5A, RL = 60Ω, VGS = 10V		55	100	ns
Turn-Off Time	t _{off}			210	350	

2SK2671

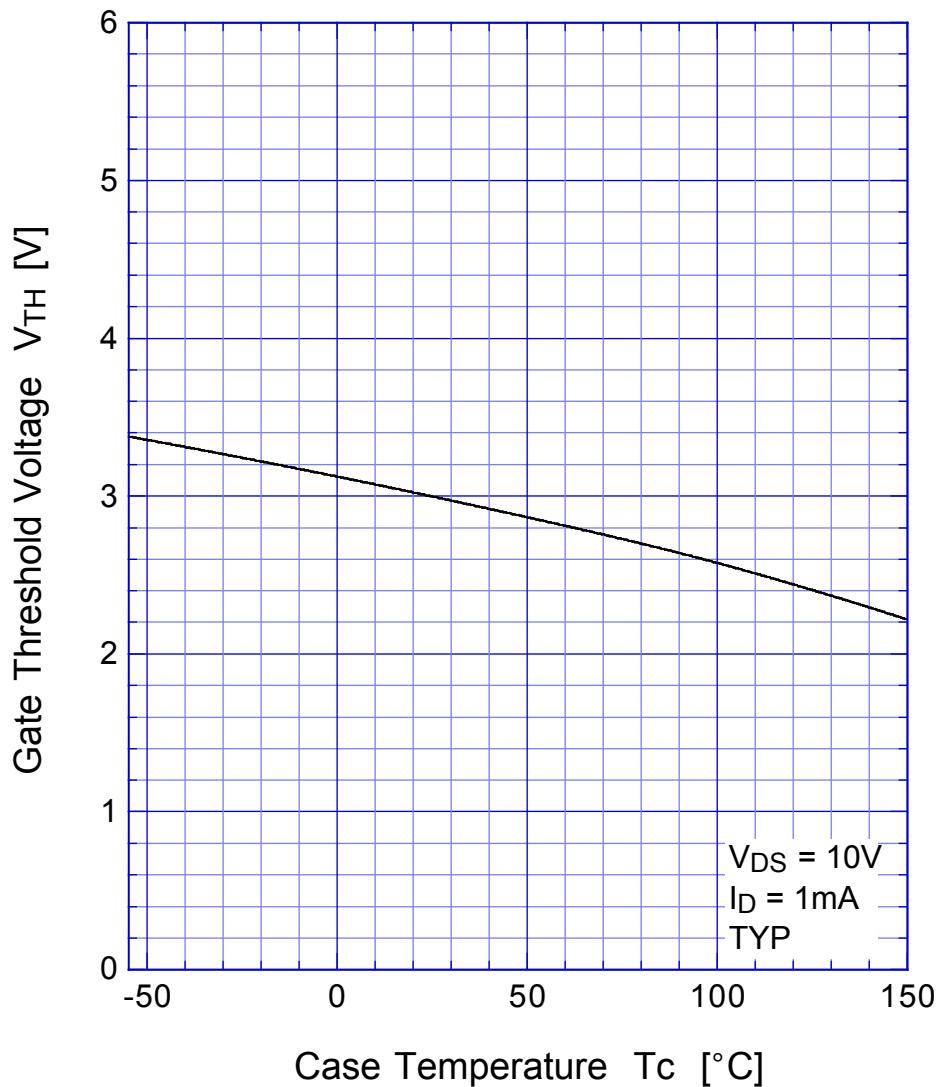
Transfer Characteristics



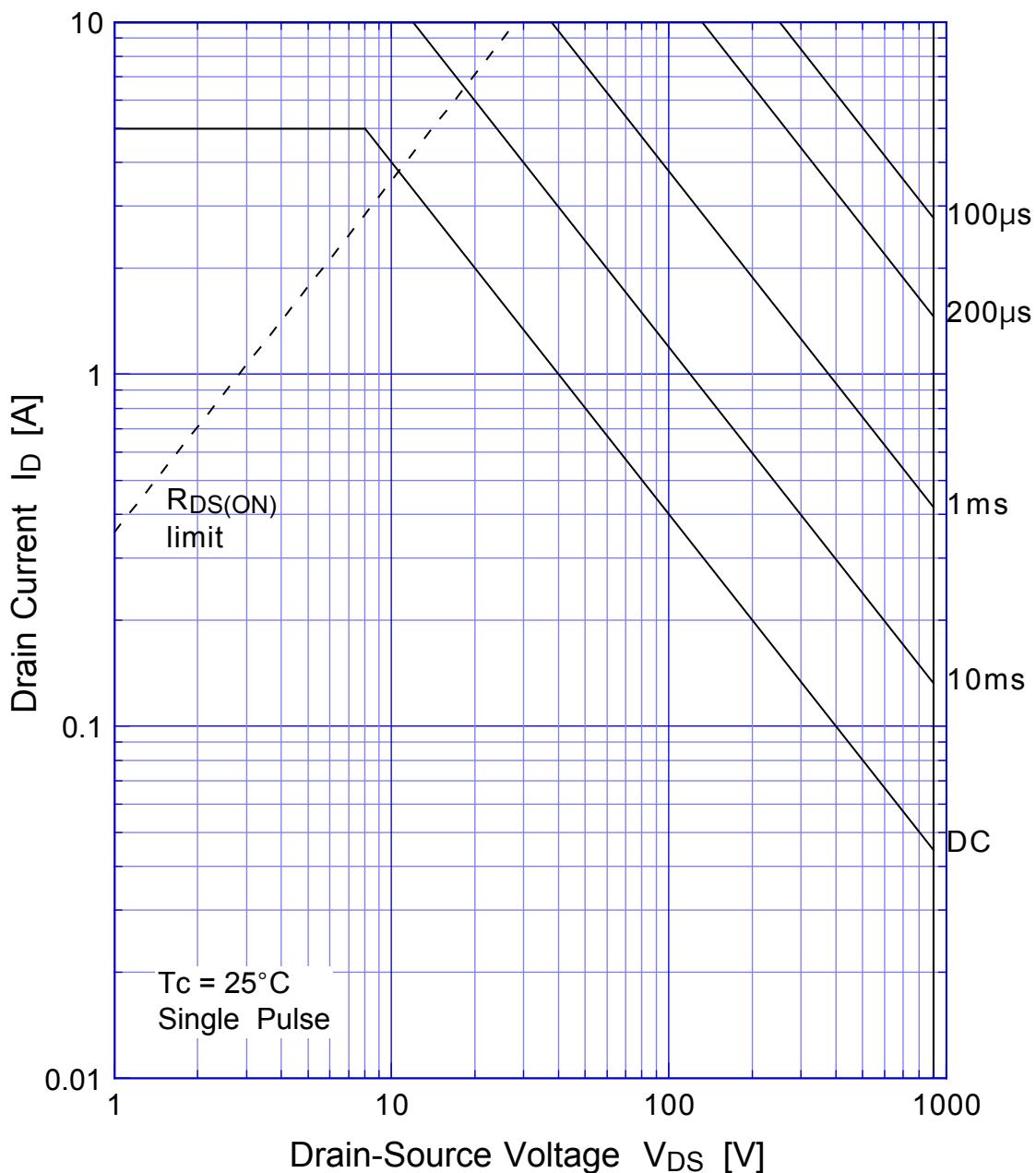
2SK2671 Static Drain-Source On-state Resistance



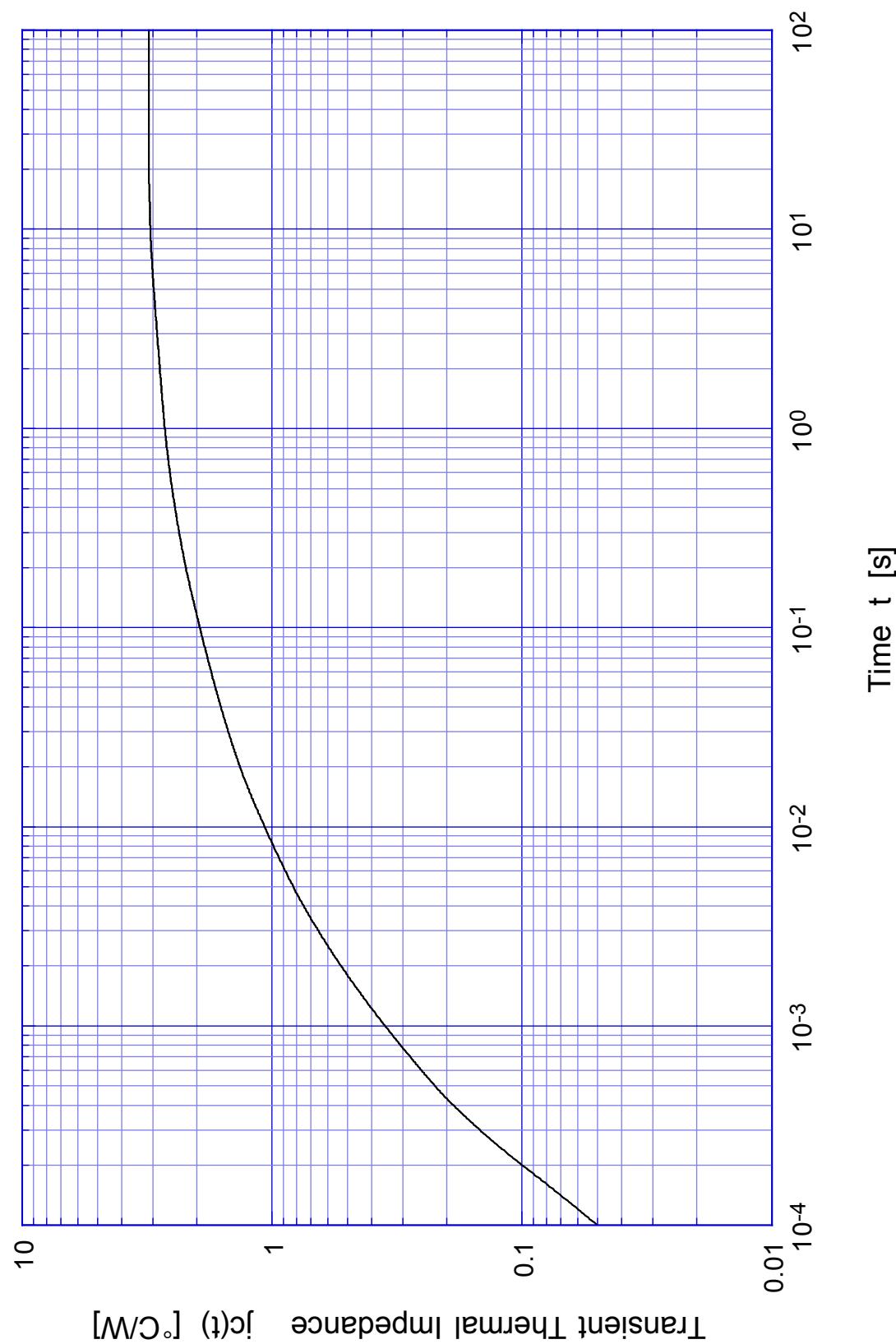
2SK2671 Gate Threshold Voltage



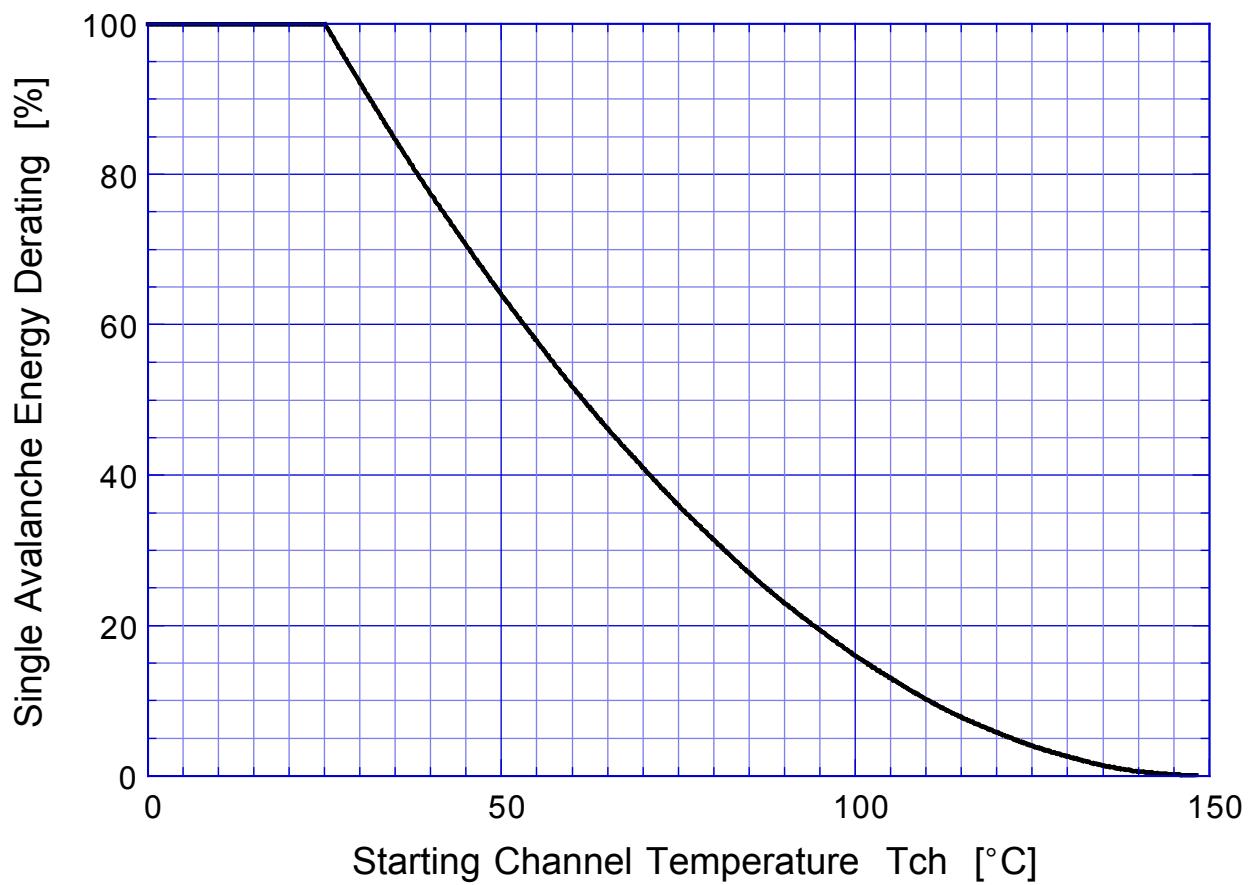
2SK2671 Safe Operating Area



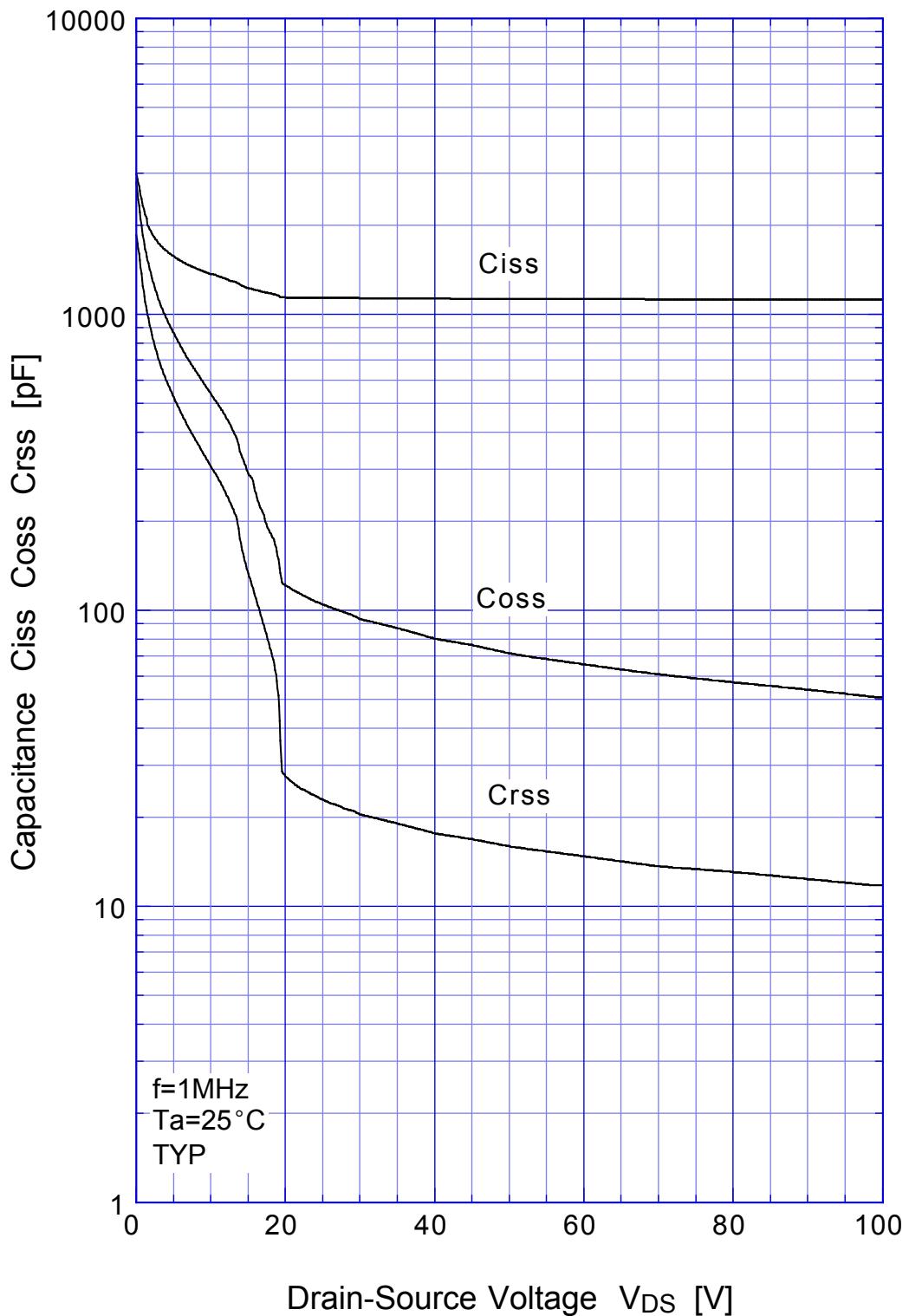
2SK2671 Transient Thermal Impedance



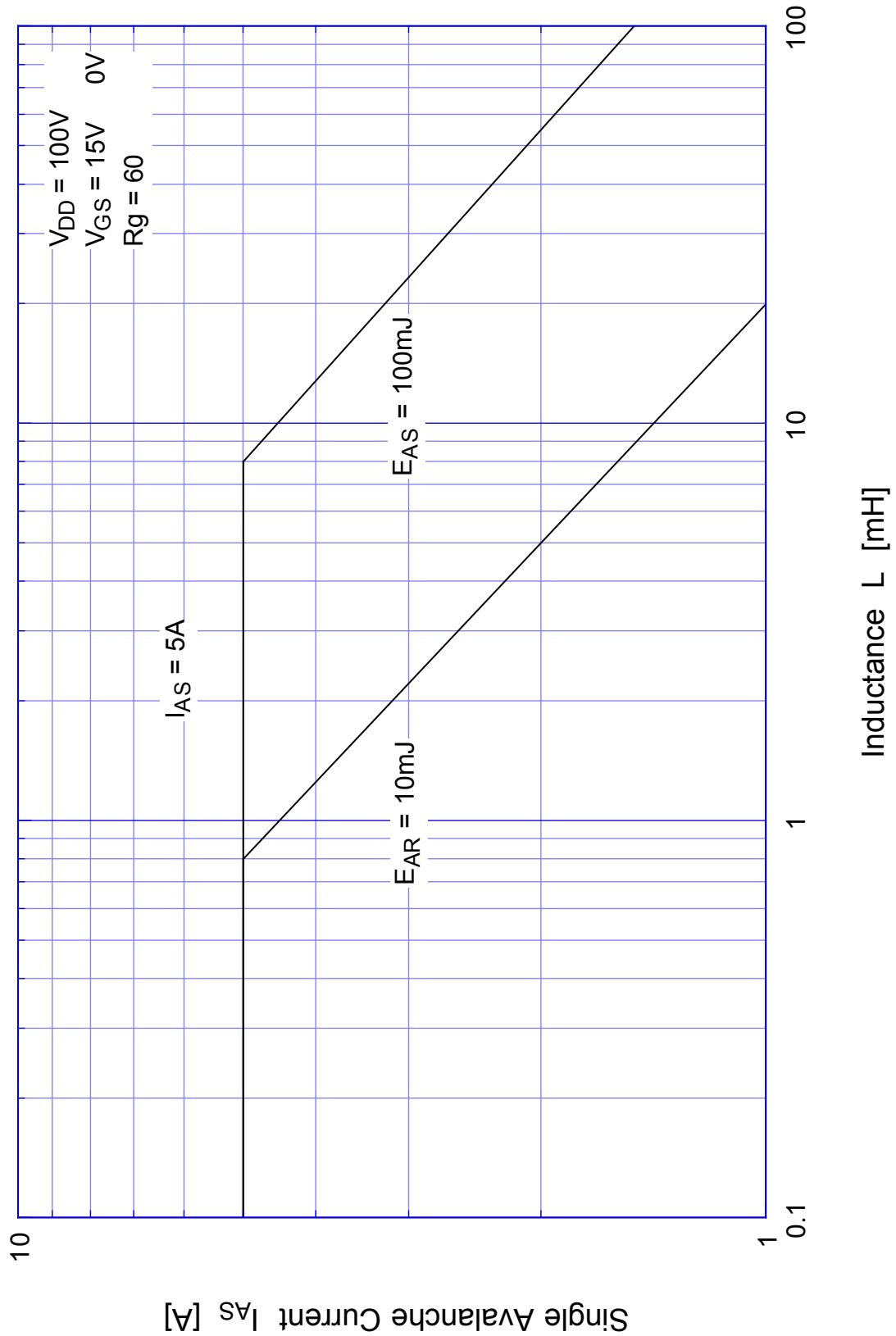
2SK2671 Single Avalanche Energy Derating



2SK2671 Capacitance

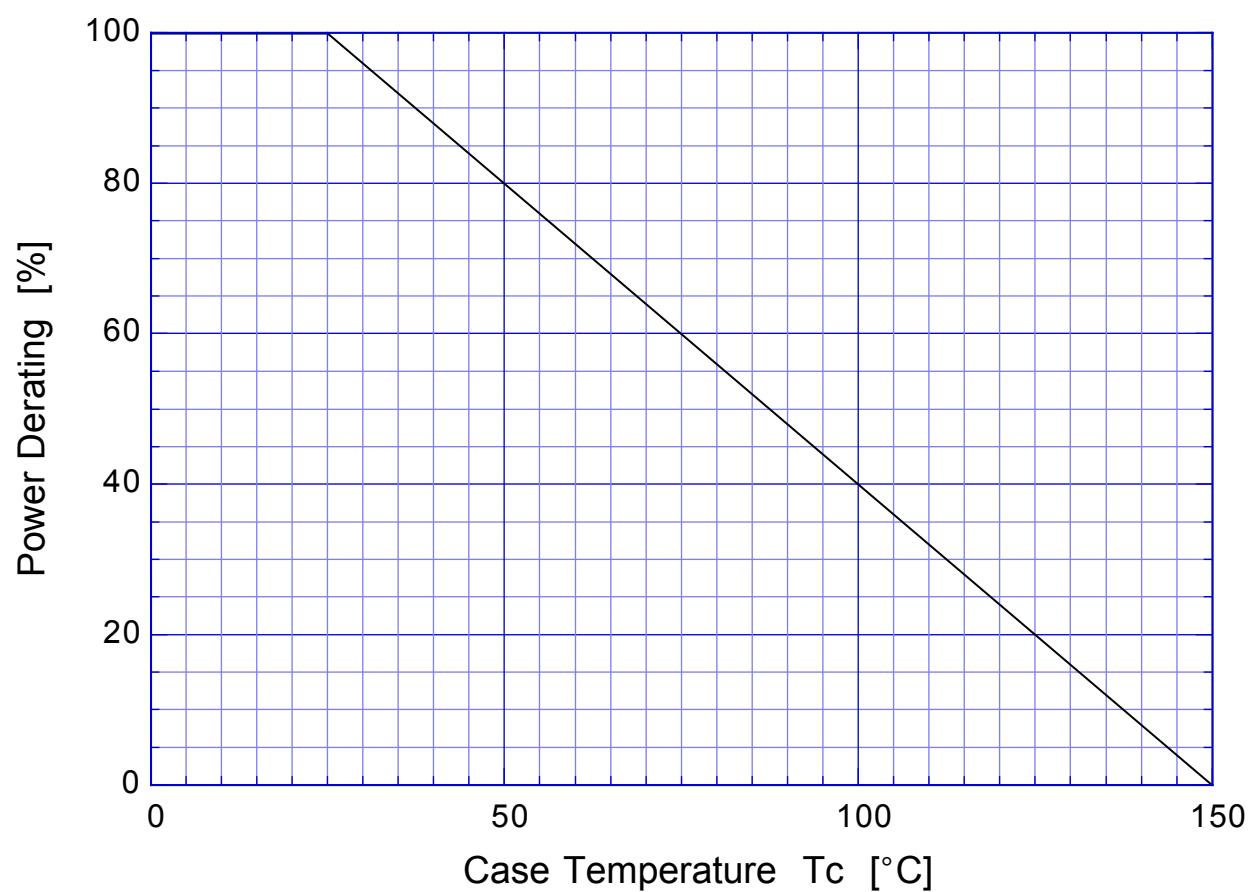


2SK2671 Single Avalanche Current - Inductive Load



2SK2671

Power Derating



2SK2671

Gate Charge Characteristics

